

## Trench Schottky Rectifier

### FEATURES

- Patented Trench Schottky technology
- Excellent high temperature stability
- Low forward voltage
- Low power loss/ High efficiency
- High forward surge capability
- Compliant to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

### TYPICAL APPLICATIONS

Trench Schottky barrier rectifier are designed for high frequency miniature switched mode power supplies such as adapters, lighting and on-board DC/DC converters.

### MECHANICAL DATA

**Case:** ITO-220AB

Molding compound meets UL 94 V-0 flammability rating

Packing code with suffix "G" means green compound (halogen-free)

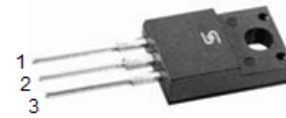
**Terminal:** Matte tin plated leads, solderable per JESD22-B102

Meet JESD 201 class 2 whisker test

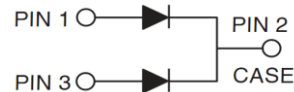
**Polarity:** As marked

**Mounting torque:** 0.56 Nm max.

**Weight:** 1.7 g (approximately)



ITO-220AB



| MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T <sub>A</sub> =25°C unless otherwise noted)  |                      |                        |                    |                |      |                |      |                |      |                |      |      |
|-----------------------------------------------------------------------------------------------|----------------------|------------------------|--------------------|----------------|------|----------------|------|----------------|------|----------------|------|------|
| PARAMETER                                                                                     |                      |                        | SYMBOL             | TSF40H<br>100C |      | TSF40H<br>120C |      | TSF40H<br>150C |      | TSF40H<br>200C |      | UNIT |
| Maximum repetitive peak reverse voltage                                                       |                      |                        | V <sub>RRM</sub>   | 100            |      | 120            |      | 150            |      | 200            |      | V    |
| Maximum average forward rectified current                                                     | per device           |                        | I <sub>F(AV)</sub> | 40             |      |                |      |                |      |                |      | A    |
|                                                                                               | per diode            |                        |                    | 20             |      |                |      |                |      |                |      |      |
| Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load per diode |                      |                        | I <sub>FSM</sub>   | 250            |      |                |      |                |      |                |      | A    |
| Voltage rate of change (Rated V <sub>R</sub> )                                                |                      |                        | dV/dt              | 10000          |      |                |      |                |      |                |      | V/μs |
|                                                                                               |                      |                        |                    | TYP.           | MAX. | TYP.           | MAX. | TYP.           | MAX. | TYP.           | MAX. |      |
| Instantaneous forward voltage per diode ( Note1 )                                             | I <sub>F</sub> = 10A | T <sub>J</sub> = 25°C  | V <sub>F</sub>     | 0.56           | -    | 0.60           | -    | 0.71           | -    | 0.75           | -    | V    |
|                                                                                               | I <sub>F</sub> = 20A |                        |                    | 0.66           | 0.72 | 0.74           | 0.84 | 0.79           | 0.89 | 0.83           | 0.93 |      |
|                                                                                               | I <sub>F</sub> = 10A | T <sub>J</sub> = 125°C | V <sub>F</sub>     | 0.48           | -    | 0.53           | -    | 0.59           | -    | 0.62           | -    |      |
|                                                                                               | I <sub>F</sub> = 20A |                        |                    | 0.59           | 0.65 | 0.63           | 0.71 | 0.67           | 0.77 | 0.70           | 0.80 |      |
| Instantaneous reverse current per diode at rated reverse voltage                              |                      | T <sub>J</sub> = 25°C  | I <sub>R</sub>     | -              | 500  | -              | 500  | -              | 150  | -              | 150  | μA   |
|                                                                                               |                      | T <sub>J</sub> = 125°C |                    | 15             | 45   | 15             | 45   | 3              | 15   | 3              | 15   | mA   |
| Typical thermal resistance per diode                                                          |                      |                        | R <sub>θJC</sub>   | 3              |      |                |      |                |      |                |      | °C/W |
| Operating junction temperature range                                                          |                      |                        | T <sub>J</sub>     | - 55 to +150   |      |                |      |                |      |                |      | °C   |
| Storage temperature range                                                                     |                      |                        | T <sub>STG</sub>   | - 55 to +150   |      |                |      |                |      |                |      | °C   |

Note 1: Pulse Test with Pulse Width=300μs, 1% Duty Cycle

| ORDERING INFORMATION   |              |                     |           |           |
|------------------------|--------------|---------------------|-----------|-----------|
| PART NO.               | PACKING CODE | PACKING CODE SUFFIX | PACKAGE   | PACKING   |
| TSF40HXXXC<br>(Note 1) | C0           | G                   | ITO-220AB | 50 / Tube |

Note 1: "XXX" defines voltage from 100V (TSF40H100C) to 200V (TSF40H200C)

| EXAMPLE            |            |              |                     |                |
|--------------------|------------|--------------|---------------------|----------------|
| PREFERRED PART NO. | PART NO.   | PACKING CODE | PACKING CODE SUFFIX | DESCRIPTION    |
| TSF40H120C C0G     | TSF40H120C | C0           | G                   | Green compound |

## RATINGS AND CHARACTERISTICS CURVES

( $T_A=25^{\circ}\text{C}$  unless otherwise noted)

FIG. 1- FORWARD CURRENT DERATING CURVE

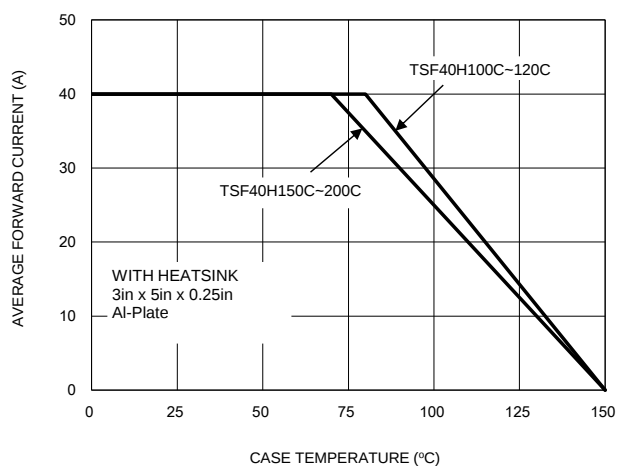


FIG. 2- TYPICAL FORWARD CHARACTERISTICS

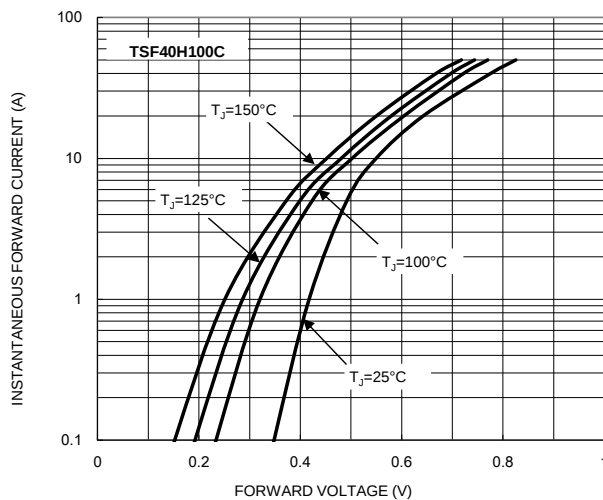


FIG. 3- TYPICAL FORWARD CHARACTERISTICS

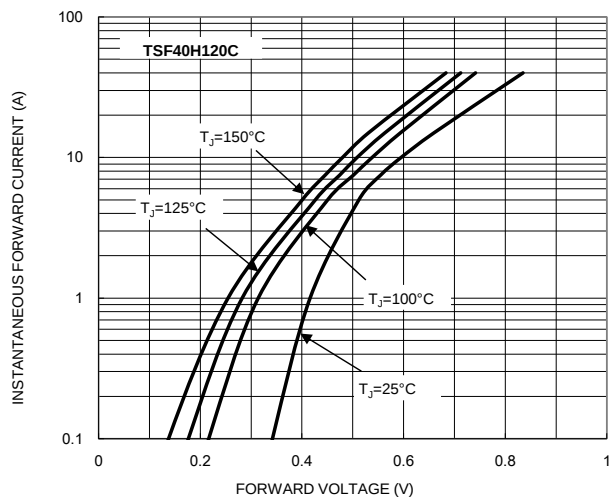


FIG. 4- TYPICAL FORWARD CHARACTERISTICS

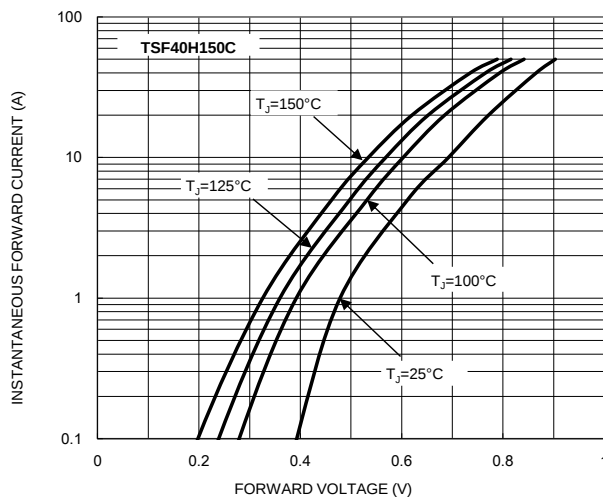


FIG. 6- TYPICAL FORWARD CHARACTERISTICS

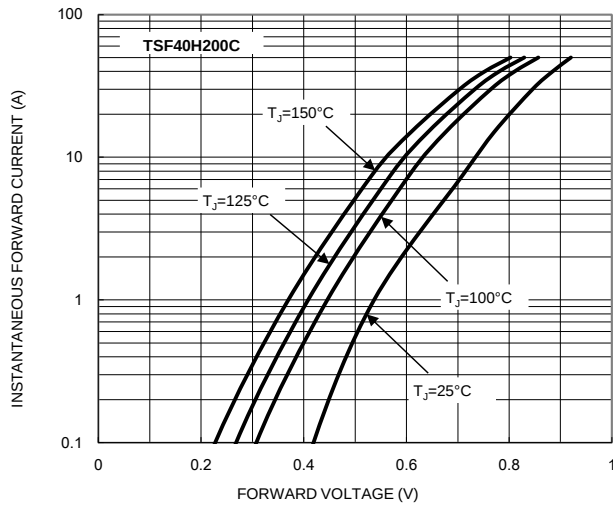


FIG. 7- TYPICAL REVERSE CHARACTERISTICS

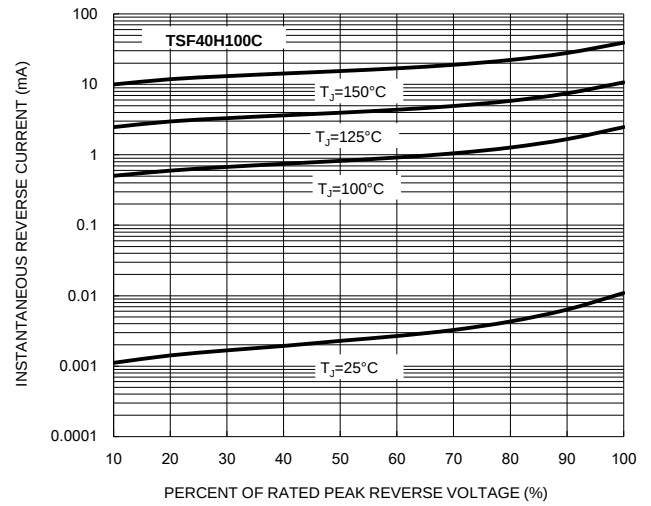


FIG. 7- TYPICAL REVERSE CHARACTERISTICS

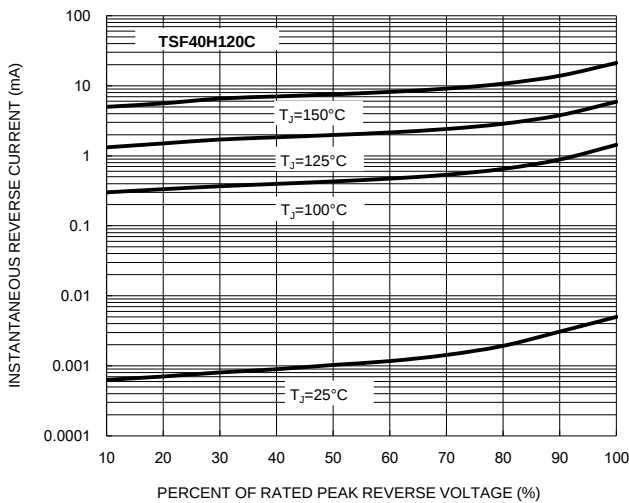


FIG. 8- TYPICAL REVERSE CHARACTERISTICS

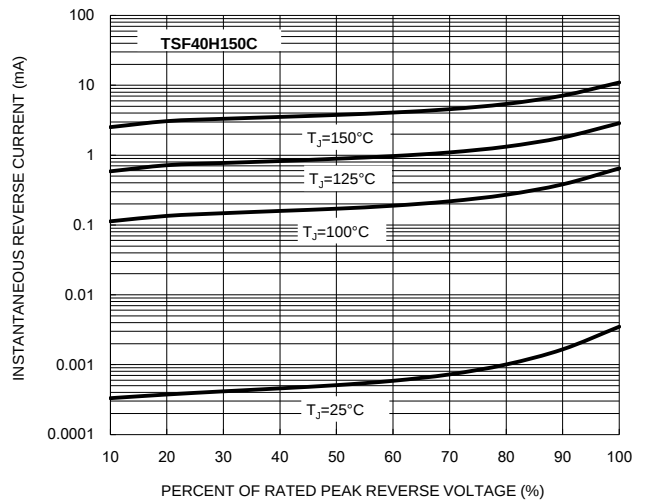


FIG. 9- TYPICAL REVERSE CHARACTERISTICS

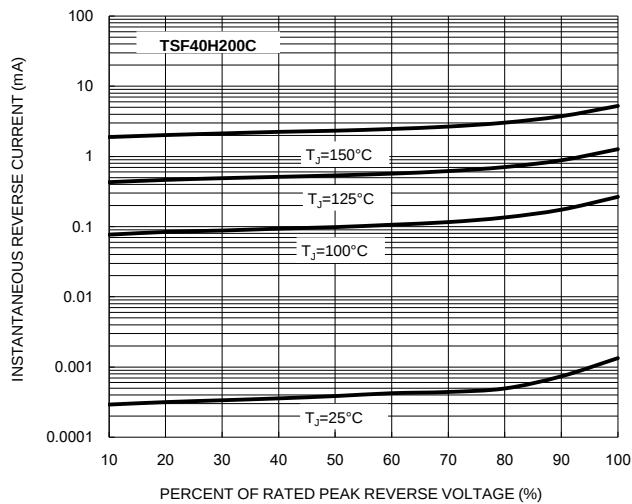
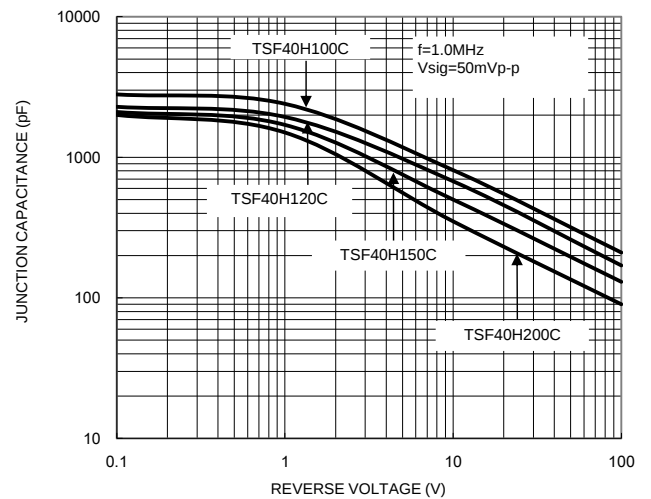
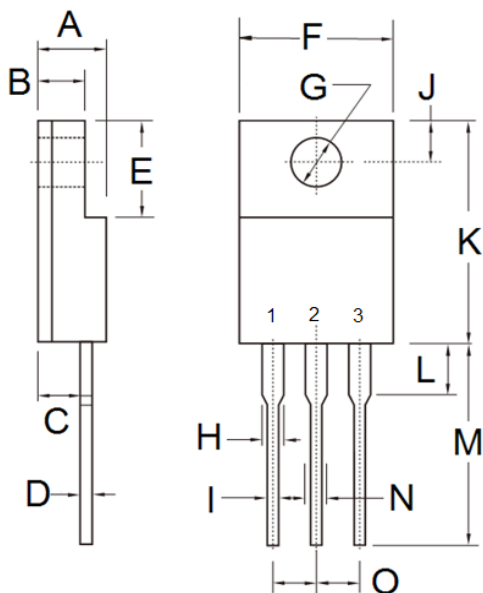


FIG. 10- TYPICAL JUNCTION CAPACITANCE



**PACKAGE OUTLINE DIMENSIONS**

ITO-220AB



| DIM. | Unit (mm) |       | Unit (inch) |      |
|------|-----------|-------|-------------|------|
|      | Min       | Max   | Min         | Max  |
| A    | 4.30      | 4.70  | 0.17        | 0.19 |
| B    | 2.50      | 3.16  | 0.10        | 0.12 |
| C    | 2.30      | 2.96  | 0.09        | 0.12 |
| D    | 0.46      | 0.76  | 0.02        | 0.03 |
| E    | 6.30      | 6.90  | 0.25        | 0.27 |
| F    | 9.60      | 10.30 | 0.38        | 0.41 |
| G    | 3.00      | 3.40  | 0.12        | 0.13 |
| H    | 0.95      | 1.45  | 0.04        | 0.06 |
| I    | 0.50      | 0.90  | 0.02        | 0.04 |
| J    | 2.40      | 3.20  | 0.09        | 0.13 |
| K    | 14.80     | 15.50 | 0.58        | 0.61 |
| L    | -         | 4.10  | -           | 0.16 |
| M    | 12.60     | 13.80 | 0.50        | 0.54 |
| N    | -         | 1.80  | -           | 0.07 |
| O    | 2.41      | 2.67  | 0.09        | 0.11 |

**MARKING DIAGRAM**



P/N = Specific Device Code  
 G = Green Compound  
 YYWW = Date Code  
 F = Factory Code

### Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.



Компания «ЭлектроПласт» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Оперативные поставки широкого спектра электронных компонентов отечественного и импортного производства напрямую от производителей и с крупнейших мировых складов;
- Поставка более 17-ти миллионов наименований электронных компонентов;
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- Лицензия ФСБ на осуществление работ с использованием сведений, составляющих государственную тайну;
- Поставка специализированных компонентов (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Aeroflex, Peregrine, Syfer, Eurofarad, Texas Instrument, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Помимо этого, одним из направлений компании «ЭлектроПласт» является направление «Источники питания». Мы предлагаем Вам помощь Конструкторского отдела:

- Подбор оптимального решения, техническое обоснование при выборе компонента;
- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

**Телефон:** 8 (812) 309 58 32 (многоканальный)

**Факс:** 8 (812) 320-02-42

**Электронная почта:** [org@eplast1.ru](mailto:org@eplast1.ru)

**Адрес:** 198099, г. Санкт-Петербург, ул. Калинина, дом 2, корпус 4, литера А.